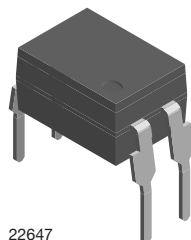
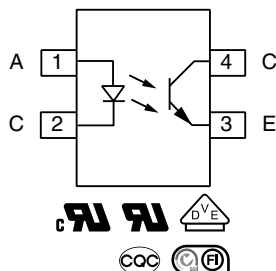


# Low Input Current Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



22647



## DESCRIPTION

The 110 °C rated VO615C series feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

## FEATURES

- Copper lead-frame
- Operating temperature from -55 °C to +110 °C
- Isolation test voltage, 5300 V<sub>RMS</sub>
- High collector emitter voltage, V<sub>CEO</sub> = 80 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
**HALOGEN**  
**FREE**  
**GREEN**  
(5-2008)

## APPLICATIONS

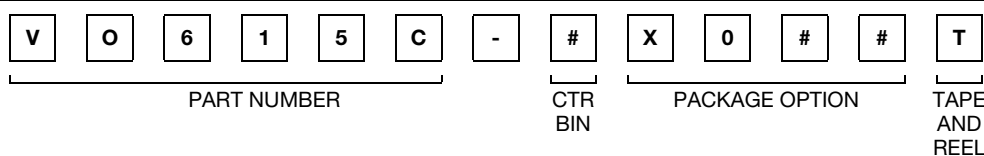
- AC adapters
- SMPS
- PLC
- Factory automation
- Game consoles

## AGENCY APPROVALS

The safety application model number covering all products in this datasheet is VO615C. This model number should be used when consulting safety agency documents.

- [UL](#)
- [cUL](#)
- [DIN EN 60747-5-5 \(VDE 0884\)](#), available with option 1
- [FIMKO](#)
- [CQC GB 4943.1-2022](#)

## ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	10 mA			
UL, cUL, FIMKO, CQC	40 to 80	63 to 125	100 to 200	160 to 320
DIP-4	VO615C-1	-	-	-
VDE, UL, cUL, FIMKO, CQC (option 1)	40 to 80	63 to 125	100 to 200	160 to 320
DIP-4, 400 mil, option 6	-	VO615C-2X016	VO615C-3X016	VO615C-4X016
SMD-4, option 9	-	VO615C-2X019T, VO615C-2X019T1 <sup>(1)</sup>	-	-

## Notes

- Additional options may be available, please contact the sales office

<sup>(1)</sup> T1 rotation in tape and reel packaging

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p \leq 10\text{ }\mu\text{s}$	$I_{FSM}$	1.5	A
Power dissipation	at $25\text{ }^{\circ}\text{C}$	$P_{diss}$	70	mW
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CEO}$	80	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
	$t_p \leq 1\text{ ms}$		100	mA
Output power dissipation	at $25\text{ }^{\circ}\text{C}$	$P_{diss}$	150	mW
<b>COUPLER</b>				
Isolation test voltage (RMS)	$t = 1\text{ min}$	$V_{ISO}$	5300	$V_{RMS}$
Total power dissipation		$P_{tot}$	200	mW
Operation temperature		$T_{amb}$	-55 to +110	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to +150	$^{\circ}\text{C}$
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
Soldering temperature <sup>(1)</sup>	2 mm from case, $\leq 10\text{ s}$	$T_{sld}$	260	$^{\circ}\text{C}$

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability
- <sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD), and wave profile for soldering conditions for through hole devices (DIP), please go to "Assembly Instructions" ([www.vishay.com/doc?80054](http://www.vishay.com/doc?80054))

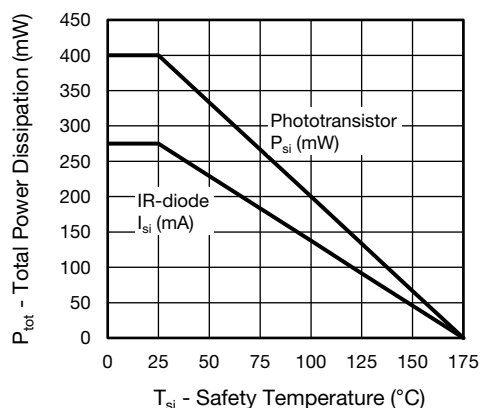


Fig. 1 - Total Power Dissipation vs. Safety Temperature

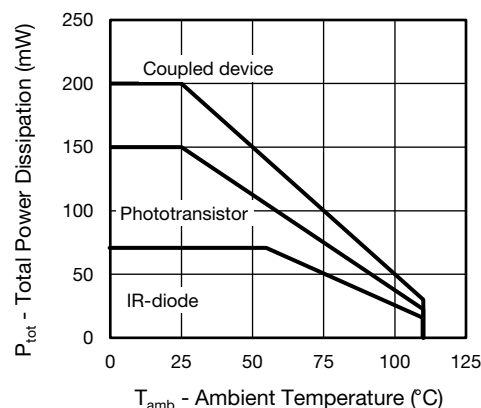


Fig. 2 - Total Power Dissipation vs. Ambient Temperature

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = 60\text{ mA}$	$V_F$		1.35	1.6	V
Reverse current	$V_R = 6\text{ V}$	$I_R$		0.01	10	$\mu\text{A}$
Junction capacitance	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$	$C_j$		9		pF
<b>OUTPUT</b>						
Collector emitter leakage current	$V_{CE} = 10\text{ V}$	$I_{CEO}$		0.3	100	nA
Collector emitter capacitance	$V_{CE} = 5\text{ V}$ , $f = 1\text{ MHz}$	$C_{CE}$		2.8		pF
Collector emitter breakdown voltage	$I_C = 1\text{ mA}$	$BV_{CEO}$	80			V
Emitter collector breakdown voltage	$I_E = 100\text{ }\mu\text{A}$	$BV_{ECO}$	7			V
<b>COUPLER</b>						
Collector emitter saturation voltage	$I_F = 10\text{ mA}$ , $I_C = 2.5\text{ mA}$	$V_{CEsat}$		0.25	0.4	V
Coupling capacitance	$f = 1\text{ MHz}$	$C_C$		0.4		pF
Cut-off frequency	$I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 100\text{ }\Omega$	$f_{ctr}$		110		kHz

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

<b>CURRENT TRANSFER RATIO</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$I_F = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$	VO615C-1	CTR	40		80	%
		VO615C-2	CTR	63		125	%
		VO615C-3	CTR	100		200	%
		VO615C-4	CTR	160		320	%

<b>SWITCHING CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>NON-SATURATED</b>						
Rise time	$I_C = 2\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 100\text{ }\Omega$	$t_r$		3		$\mu\text{s}$
Fall time		$t_f$		3		$\mu\text{s}$
Turn-on time		$t_{on}$		6		$\mu\text{s}$
Turn-off time		$t_{off}$		4		$\mu\text{s}$

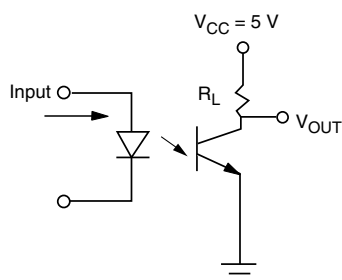


Fig. 3 - Test Circuit

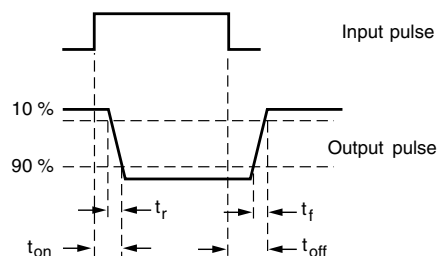


Fig. 4 - Test Circuit and Waveforms

SAFETY AND INSULATION RATINGS				
PARAMETER		SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS				
Output safety power		$P_{SO}$	700	mW
Input safety current		$I_{si}$	400	mW
Safety temperature		$T_S$	175	°C
Comparative tracking index		CTI	175	
INSULATION RATED PARAMETERS				
Maximum withstanding isolation voltage		$V_{ISO}$	5300	$V_{RMS}$
Maximum transient isolation voltage		$V_{IOTM}$	8000	$V_{peak}$
Maximum repetitive peak isolation voltage		$V_{IORM}$	565	$V_{peak}$
		$V_{IORM}^{(1)}$	1140	$V_{peak}$
Insulation resistance	$T_{amb} = 25\text{ °C}, V_{DC} = 500\text{ V}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
Isolation resistance	$T_{amb} = 100\text{ °C}, V_{DC} = 500\text{ V}$	$R_{IO}$	$\geq 10^{11}$	$\Omega$
Climatic classification (according to IEC 68 part 1)			55/110/21	
Environment (pollution degree in accordance to DIN VDE 0109)			2	
Internal and external creepage	Standard DIP-4		$\geq 7$	mm
	400 mil DIP-4		$\geq 8$	mm
Clearance	Standard DIP-4		$\geq 7$	mm
	400 mil DIP-4		$\geq 8$	mm
Insulation thickness			0.4	mm

**Notes**

- As per DIN EN 60747-5-5, 2, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits

<sup>(1)</sup> Only for option 6.

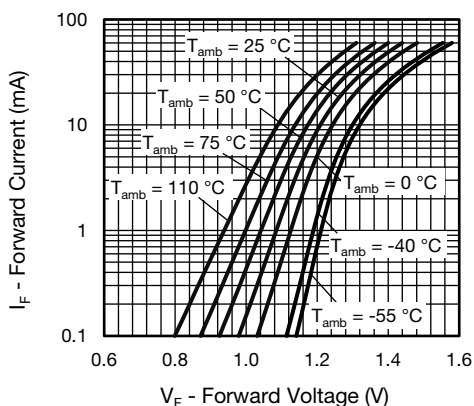
**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ °C}$ , unless otherwise specified)


Fig. 5 - Forward Voltage vs. Forward Current

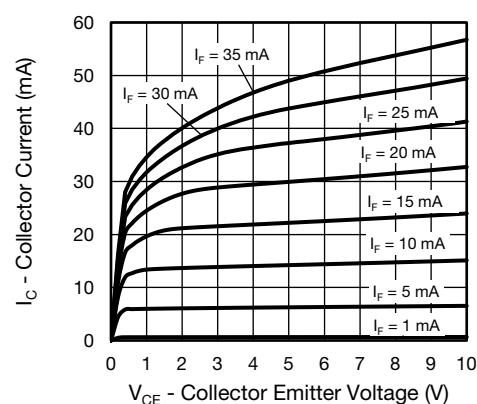


Fig. 6 - Collector Current vs. Collector Emitter Voltage (NS)

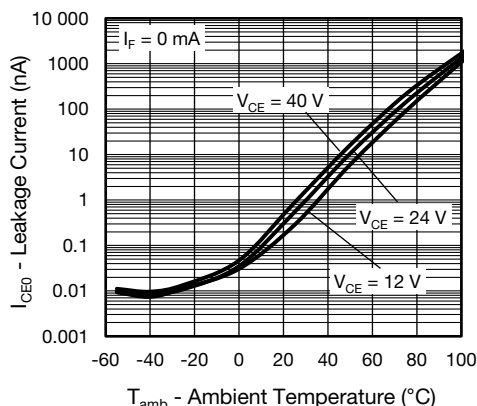


Fig. 7 - Leakage Current vs. Ambient Temperature

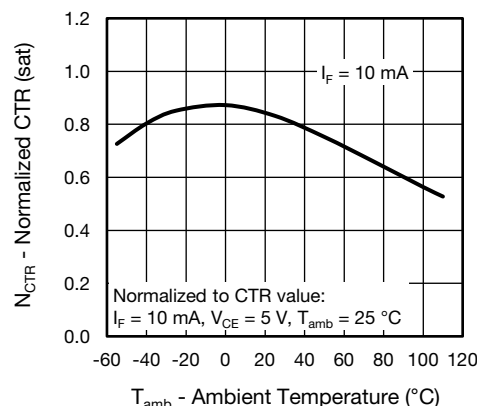


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature

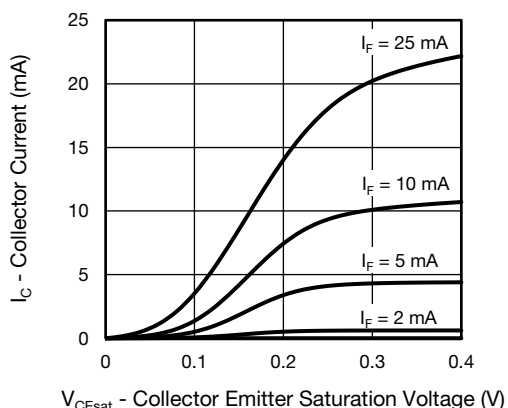


Fig. 8 - Collector Current vs. Collector Emitter Voltage (saturated)

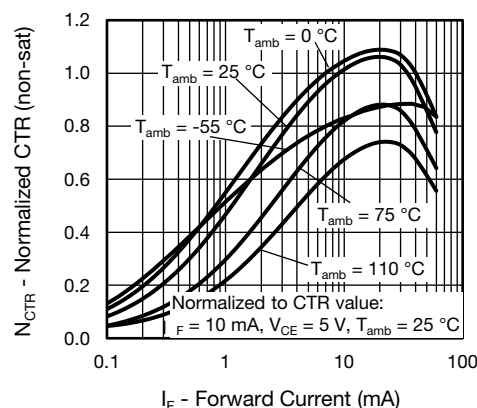


Fig. 11 - Normalized CTR (non-saturated) vs. Forward Current

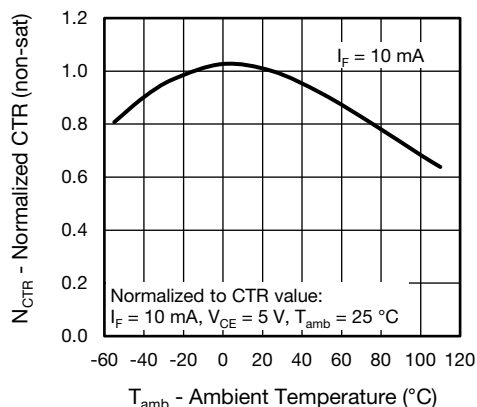


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs. Ambient Temperature

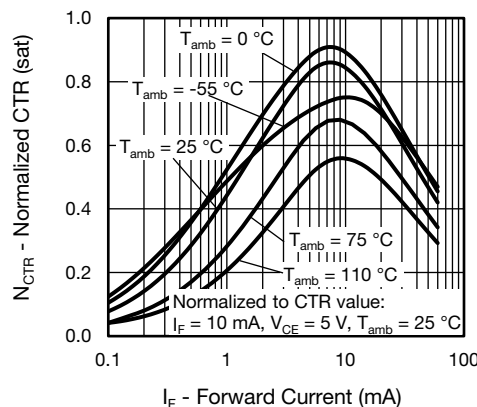


Fig. 12 - Normalized CTR (saturated) vs. Forward Current

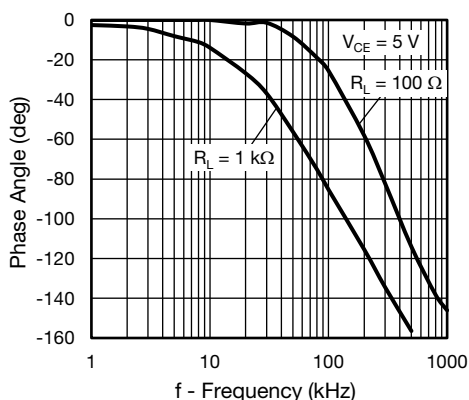


Fig. 13 - Phase Angle vs. Frequency

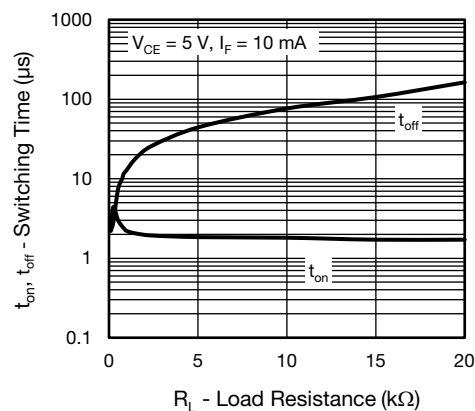


Fig. 15 - Switching Time vs. Load Resistance

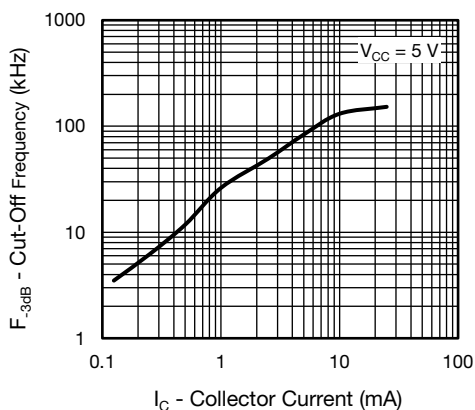


Fig. 14 - Frequency vs. Collector Current

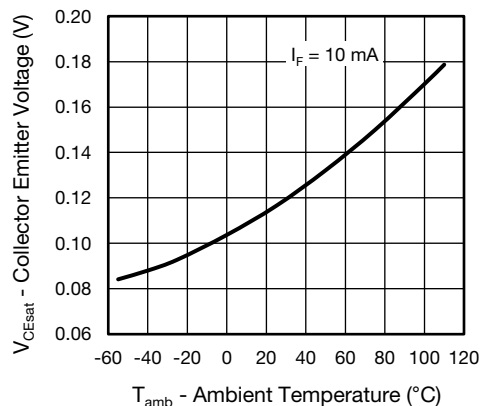
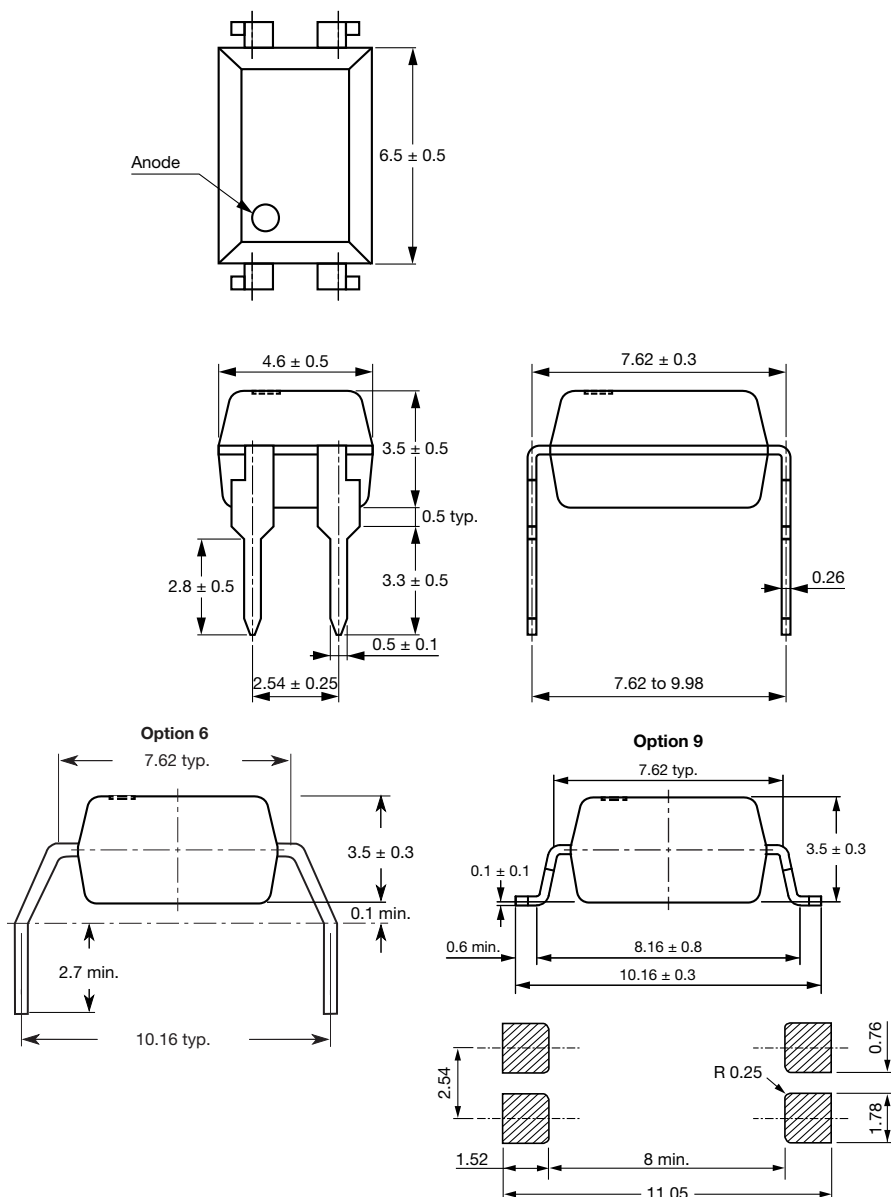
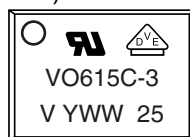


Fig. 16 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

**PACKAGE DIMENSIONS** in millimeters

**PACKAGE MARKING** (Example of VO615C-3X016)

**Note**

- Option information is not marked

**PACKING INFORMATION**

DEVICE PER TUBE			
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX
DIP-4	100	40	4000

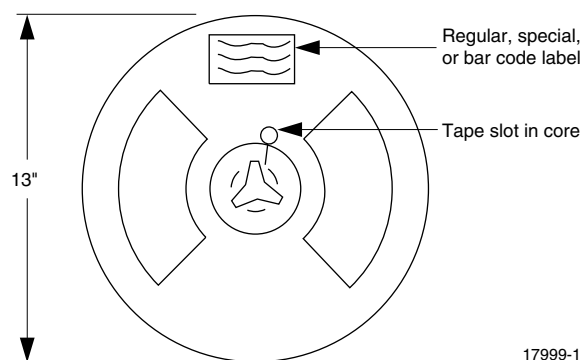


Fig. 17 - Tape and Reel Shipping Medium

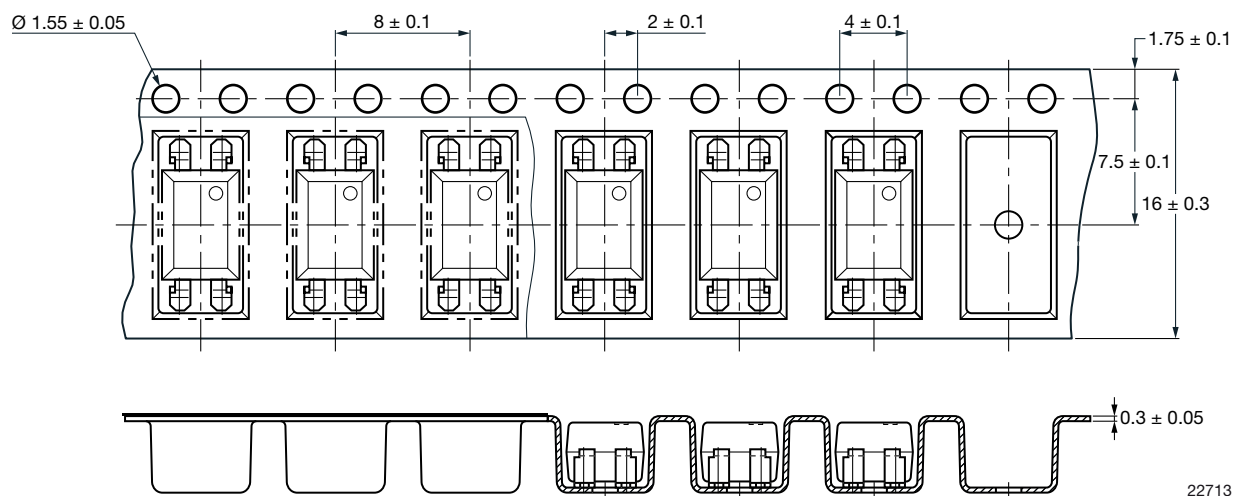


Fig. 18 - Tape Packing for Option 7 and 9, T1 rotation (2000 units per reel)





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